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# 3-V TO 5.5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER WITH ±15-kV ESD PROTECTION

#### **FEATURES**

- RS-232 Bus-Pin ESD Protection Exceeds ±15 kV Using Human-Body Model (HBM)
- Meets or Exceeds the Requirements of TIA/EIA-232-F and ITU v.28 Standards
- Operates With 3-V to 5.5-V V<sub>CC</sub> Supply
- Operates Up To 250 kbit/s
- Two Drivers and Two Receivers
- Low Supply Current . . . 300 μA Typical
- External Capacitors . . . 4 × 0.1 μF
- Accepts 5-V Logic Input With 3.3-V Supply
- Alternative High-Speed Pin-Compatible Device (1 Mbit/s)
  - SNx5C3232

# SUPPORTS DEFENSE, AEROSPACE, AND MEDICAL APPLICATIONS

- Controlled Baseline
- One Assembly/Test Site
- One Fabrication Site
- Available in Military (–55°C/125°C)
   Temperature Range<sup>(1)</sup>
- Extended Product Life Cycle
- Extended Product-Change Notification
- Product Traceability
- (1) Additional temperature ranges are available contact factory

#### ORDERING INFORMATION<sup>(1)</sup>

| T <sub>A</sub> | PAC       | KAGE <sup>(2)</sup> | ORDERABLE PART NUMBER | TOP-SIDE MARKING |
|----------------|-----------|---------------------|-----------------------|------------------|
| FF00 +- 10F00  | SSOP (DB) | Reel of 2000        | MAX3232MDBREP         | MB3232M          |
| –55°C to 125°C | TSSOP(PW) | Reel of 2000        | MAX3232MPWREP         | IVIDSZJZIVI      |

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.
- (2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

#### DESCRIPTION

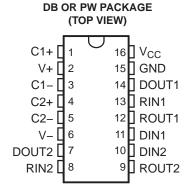
The MAX3232 device consists of two line drivers, two line receivers, and a dual charge-pump circuit with  $\pm 15$ -kV ESD protection pin to pin (serial-port connection pins, including GND). The device meets the requirements of TIA/EIA-232-F and provides the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 3-V to 5.5-V supply. The devices operate at data signaling rates up to 250 kbit/s and a maximum of 30-V/ $\mu$ s driver output slew rate.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

#### **APPLICATIONS**

 Battery-Powered Systems, PDAs, Notebooks, Laptops, Palmtop PCs, and Hand-Held Equipment

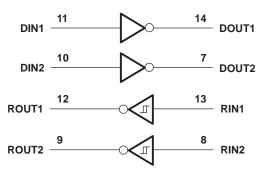




#### **FUNCTION TABLE**

| EACH   | DRIVER      | EACH RECEIVER |             |  |  |  |  |  |  |
|--|-------------|---------------|-------------|--|--|--|--|--|--|
| INPUT DIN  | OUTPUT DOUT | INPUT RIN     | OUTPUT ROUT |  |  |  |  |  |  |
| L  | Н           | L             | Н           |  |  |  |  |  |  |
| Н  | L           | Н             | L           |  |  |  |  |  |  |
|  |             | Open          | Н           |  |  |  |  |  |  |
| H = high level, L = low level, Open = input disconnected or connected driver off |             |               |             |  |  |  |  |  |  |

#### **LOGIC DIAGRAM (POSITIVE LOGIC)**



#### **ABSOLUTE MAXIMUM RATINGS**

over operating free-air temperature range (unless otherwise noted)

|                  | ·  |  | VALUE      | UNIT |  |  |
|------------------|--|--|------------|------|--|--|
| V <sub>CC</sub>  | Supply voltage range <sup>(1)</sup>      | 1  | -0.3 to 6  | V    |  |  |
| V+               | Positive output supply voltage range (1) | -0.3 to 7                                      | V          |      |  |  |
| V–               | Negative output supply voltage range (1) | 0.3 to -7                                      | V          |      |  |  |
| V+ - V-          | Supply voltage difference <sup>(1)</sup> | 13   | V          |      |  |  |
| V <sub>I</sub>   | Input voltage range                      | Drivers  | -0.3 to 6  | V    |  |  |
|                  |  | Receivers                                      | -25 to 25  | V    |  |  |
| .,               | Output voltage range                     | Output voltage range Drivers                   |            |      |  |  |
| Vo               |  | Receivers                                      |            |      |  |  |
| $\theta_{JA}$    | Package thermal impedance <sup>(2)</sup> | DB package                                     | 82         | °C/W |  |  |
|                  |  | 108  | °C/W       |      |  |  |
| ГЈ               | Operating virtual junction temperature   | <u>,                                      </u> | 150        | °C   |  |  |
| T <sub>stg</sub> | Storage temperature range                |  | -65 to 150 | °C   |  |  |

<sup>(1)</sup> All voltages are with respect to network GND.

# RECOMMENDED OPERATING CONDITIONS (see (1) and Figure 4)

|                 |                                 |     |                          | MIN | NOM | MAX | UNIT |
|-----------------|---------------------------------|-----|--------------------------|-----|-----|-----|------|
|                 | Cumply yellogo                  |     | $V_{CC} = 3.3 \text{ V}$ | 3   | 3.3 | 3.6 | V    |
|                 | Supply voltage                  |     |                          |     | 5   | 5.5 | V    |
| \/              | Driver high level input valtege | DIN | V <sub>CC</sub> = 3.3 V  | 2   |     |     | V    |
| V <sub>IH</sub> | Driver high-level input voltage | DIN | V <sub>CC</sub> = 5 V    | 2.4 |     |     | V    |
| $V_{IL}$        | Driver low-level input voltage  | DIN |                          |     |     | 8.0 | V    |

(1) Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V ±0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V ±0.5 V.

Maximum power dissipation is a function of  $T_J(max)$ ,  $\theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any allowable ambient temperature is  $P_D = (T_J(max) - T_A)/\theta_{JA}$ . Operating at the absolute maximum  $T_J$  of 150°C can affect reliability.

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### RECOMMENDED OPERATING CONDITIONS (see and Figure 4) (continued)

|                |                                | MIN      | NOM MA | X UNIT |   |       |
|----------------|--------------------------------|----------|--------|--------|---|-------|
| V.             | Driver input voltage           | DIN      |        | 0      | 5 | .5    |
| VI             | Receiver input voltage         | -25      |        | 25 V   |   |       |
| T <sub>A</sub> | Operating free-air temperature | MAX3232M |        | -55    | 1 | 25 °C |

#### **ELECTRICAL CHARACTERISTICS**

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see (1) and Figure 4)

| PARAMETER       |                | TEST CONDITIONS                         | MIN | TYP <sup>(2)</sup> | MAX | UNIT |
|-----------------|----------------|---|-----|--------------------|-----|------|
| I <sub>CC</sub> | Supply current | No load, V <sub>CC</sub> = 3.3 V or 5 V |     | 0.3                | 2   | mA   |

Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V ±0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V ±0.5 V. All typical values are at V<sub>CC</sub> = 3.3 V or V<sub>CC</sub> = 5 V, and T<sub>A</sub> = 25°C.



#### **DRIVER SECTION**

#### **ELECTRICAL CHARACTERISTICS**

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see (1) and Figure 4)

|                     | PARAMETER                    | TEST CONDI                                | TEST CONDITIONS       |            |       | MAX | UNIT |
|---------------------|------------------------------|---|-----------------------|------------|-------|-----|------|
| V <sub>OH</sub>     | High-level output voltage    | DOUT at $R_L = 3 \text{ k}\Omega$ to GND, | DIN = GND             | 5          | 5.4   |     | V    |
| V <sub>OL</sub>     | Low-level output voltage     | DOUT at $R_L = 3 \text{ k}\Omega$ to GND, | DIN = V <sub>CC</sub> | <b>-</b> 5 | -5.4  |     | V    |
| I <sub>IH</sub>     | High-level input current     | $V_I = V_{CC}$                            |                       |            | ±0.01 | ±1  | μΑ   |
| I <sub>IL</sub>     | Low-level input current      | V <sub>I</sub> at GND                     |                       |            | ±0.01 | ±1  | μΑ   |
| ı (3)               | Chart aircuit autaut aurrent | V <sub>CC</sub> = 3.6 V,                  | V <sub>O</sub> = 0 V  |            | 105   | 160 | A    |
| I <sub>OS</sub> (3) | Short-circuit output current | V <sub>CC</sub> = 5.5 V,                  | V <sub>O</sub> = 0 V  |            | ±35   | ±60 | mA   |
| ro                  | Output resistance            | $V_{CC}$ , V+, and V- = 0 V,              | V <sub>O</sub> = ±2 V | 300        | 10M   |     | Ω    |

#### **SWITCHING CHARACTERISTICS**

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see (1) and Figure 4)

|                    | PARAMETER                         | TEST CON   | MIN  | TYP <sup>(2)</sup> | MAX | UNIT |                      |
|--------------------|-----------------------------------|--|--|--------------------|-----|------|----------------------|
| Maximum data rate  |                                   | C <sub>L</sub> = 1000 pF,<br>One DOUT switching, | $R_L = 3 k\Omega$ ,<br>See Figure 1                                      | 150                | 250 |      | kbit/s               |
| t <sub>sk(p)</sub> | Pulse skew <sup>(1)</sup>         | CL = 150 pF to 2500 pF                           | $R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega,$<br>See Figure 2 |                    | 300 |      | ns                   |
| CD/tr)             | Slew rate, transition region (see | RL = $3 k\Omega$ to $7 k\Omega$ ,                | C <sub>L</sub> = 150 pF to 1000 pF                                       | 6                  |     | 30   | V/us                 |
| SR(tr)             | Figure 1)                         | $V_{CC} = 3.3 \text{ V}$                         | C <sub>L</sub> = 150 pF to 2500 pF                                       | 4                  |     | 30   | <b>ν</b> /μ <b>S</b> |

Short-circuit durations should be controlled to prevent exceeding the device absolute power dissipation ratings, and not more than one output should be shorted at a time.

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Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V ±0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V ±0.5 V. All typical values are at V<sub>CC</sub> = 3.3 V or V<sub>CC</sub> = 5 V, and T<sub>A</sub> = 25°C. Short-circuit durations should be controlled to prevent exceeding the device absolute power dissipation ratings, and not more than one output should be shorted at a time.

All typical values are at  $V_{CC}$  = 3.3 V or  $V_{CC}$  = 5 V, and  $T_A$  = 25°C.



#### RECEIVER SECTION

#### **ELECTRICAL CHARACTERISTICS**

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted (see (1) and Figure 4)

|                    | PARAMETER   | TEST CONDITIONS                              | MIN                  | TYP <sup>(2)</sup>   | MAX | UNIT |  |
|--------------------|---|--|----------------------|----------------------|-----|------|--|
| $V_{OH}$           | High-level output voltage                               | I <sub>OH</sub> = -1 mA                      | V <sub>CC</sub> -0.6 | V <sub>CC</sub> -0.1 |     | V    |  |
| $V_{OL}$           | Low-level output voltage                                | I <sub>OL</sub> = 1.6 mA                     |                      |                      | 0.4 | V    |  |
| V <sub>IT+</sub> P | Positive going input threshold voltage                  | $V_{CC} = 3.3 \text{ V}$                     |                      | 1.5                  | 2.4 | V    |  |
|                    | Positive-going input threshold voltage                  | V <sub>CC</sub> = 5 V                        |                      | 1.8                  | 2.4 | V    |  |
| V                  | No notive project insert the collected walks and        | V <sub>CC</sub> = 3.3 V                      | 0.6                  | 1.2                  |     | V    |  |
| $V_{IT-}$          | Negative-going input threshold voltage                  | V <sub>CC</sub> = 5 V                        | 0.8                  | 1.5                  |     | V    |  |
| $V_{hys}$          | Input hysteresis (V <sub>IT+</sub> – V <sub>IT-</sub> ) |  |                      | 0.3                  |     | V    |  |
| r <sub>i</sub>     | Input resistance  | $V_I = \pm 3 \text{ V to } \pm 25 \text{ V}$ | 3                    | 5                    | 8   | kΩ   |  |

- Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V ±0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V ±0.5 V. All typical values are at V<sub>CC</sub> = 3.3 V or V<sub>CC</sub> = 5 V and T<sub>A</sub> = 25°C.

#### **SWITCHING CHARACTERISTICS**

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted (see (1) and Figure 3)

|                    | PARAMETER   | TEST CONDITIONS        | MIN | TYP <sup>(2)</sup> | MAX | UNIT |
|--------------------|---|------------------------|-----|--------------------|-----|------|
| t <sub>PLH</sub>   | Propagation delay time, low- to high-level output | C 150 pF               |     | 300                |     | ns   |
| $t_{PHL}$          | Propagation delay time, high- to low-level output | $C_L = 150 \text{ pF}$ |     | 300                |     | ns   |
| t <sub>sk(p)</sub> | Pulse skew <sup>(3)</sup>                         |                        |     | 300                |     | ns   |

- Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V ±0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V ±0.5 V.
- All typical values are at  $V_{CC} = 3.3 \text{ V}$  or  $V_{CC} = 5 \text{ V}$  and  $T_A = 25 ^{\circ}\text{C}$ .
- Pulse skew is defined as |t<sub>PLH</sub> t<sub>PHL</sub>| of each channel of the same device.

#### PARMETER MEASUREMENT INFORMATION

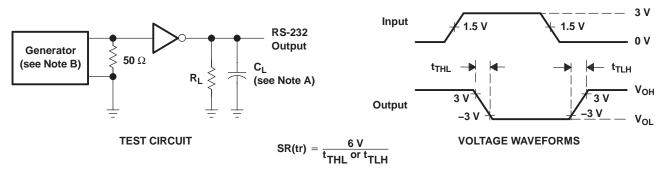
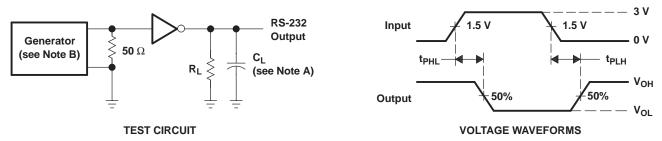


Figure 1. Driver Slew Rate



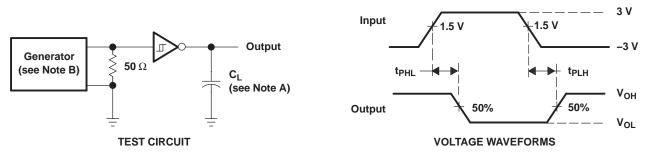
- C<sub>L</sub> includes probe and jig capacitance.
- The pulse generator has the following characteristics:  $Z_0 = 50 \Omega$ , 50% duty cycle, tr  $\leq 10$  ns, tf  $\leq 10$  ns.

Figure 2. Driver Pulse Skew

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# PARMETER MEASUREMENT INFORMATION (continued)

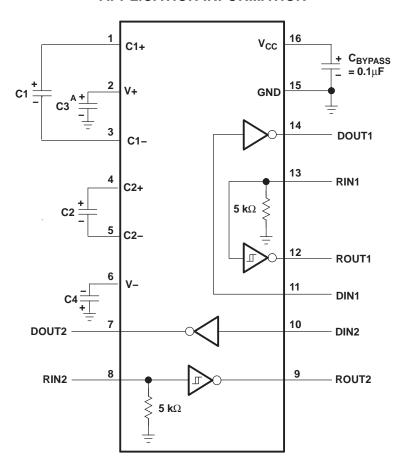


- A. C<sub>L</sub> includes probe and jig capacitance.
- B. The pulse generator has the following characteristics:  $Z_0 = 50~\Omega, 50\%$  duty cycle, tr  $\leq 10~ns$ , tf  $\leq 10~ns$ .

Figure 3. Receiver Propagation Delay Times



#### **APPLICATION INFORMATION**



V<sub>CC</sub> vs CAPACITOR VALUES

| V <sub>CC</sub>  | C1                           | C2, C3, C4                   |
|--|------------------------------|------------------------------|
| $\begin{array}{c} \textbf{3.3 V} \pm \textbf{0.3 V} \\ \textbf{5 V} \pm \textbf{0.5 V} \\ \textbf{3 V to 5.5 V} \end{array}$ | 0.1 μF<br>0.047 μF<br>0.1 μF | 0.1 μF<br>0.33 μF<br>0.47 μF |

- A. C3 can be connected to  $V_{CC}$  or GND.
- B. Resistor values shown are nominal.
- C. Nonpolarized ceramic capacitros are acceptable. If polarized tantalum or electrolytic capacitors are used, they should be connected as shown.

Figure 4. Typical Operating Circuit and Capacitor Values







10-Dec-2020

#### **PACKAGING INFORMATION**

| Orderable Device | Status (1) | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan     | Lead finish/<br>Ball material | MSL Peak Temp      | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|------------|--------------|--------------------|------|----------------|--------------|-------------------------------|--------------------|--------------|----------------------|---------|
| MAX3232MDBREP    | ACTIVE     | SSOP         | DB                 | 16   | 2000           | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM | -55 to 125   | MB3232M              | Samples |
| MAX3232MPWREP    | ACTIVE     | TSSOP        | PW                 | 16   | 2000           | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM | -55 to 125   | MB3232M              | Samples |
| V62/06623-01XE   | ACTIVE     | SSOP         | DB                 | 16   | 2000           | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM | -55 to 125   | MB3232M              | Samples |
| V62/06623-01YE   | ACTIVE     | TSSOP        | PW                 | 16   | 2000           | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM | -55 to 125   | MB3232M              | Samples |

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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## **PACKAGE OPTION ADDENDUM**

10-Dec-2020

continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF MAX3232-EP:

NOTE: Qualified Version Definitions:

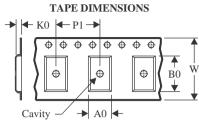
• Catalog - TI's standard catalog product

# **PACKAGE MATERIALS INFORMATION**

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#### TAPE AND REEL INFORMATION





| A0 | Dimension designed to accommodate the component width     |
|----|---|
| В0 | Dimension designed to accommodate the component length    |
| K0 | Dimension designed to accommodate the component thickness |
| W  | Overall width of the carrier tape                         |
| P1 | Pitch between successive cavity centers                   |

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

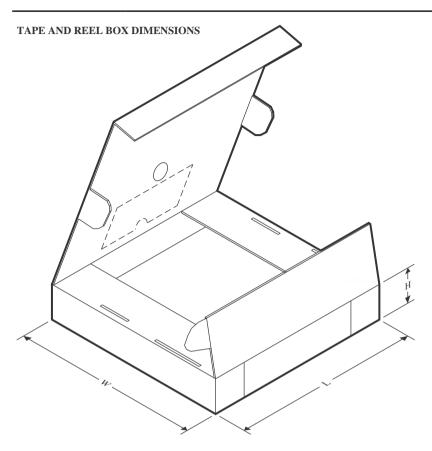


#### \*All dimensions are nominal

| Device        | Package<br>Type | Package<br>Drawing |    | SPQ  | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
|---------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| MAX3232MDBREP | SSOP            | DB                 | 16 | 2000 | 330.0                    | 16.4                     | 8.35       | 6.6        | 2.5        | 12.0       | 16.0      | Q1               |
| MAX3232MPWREP | TSSOP           | PW                 | 16 | 2000 | 330.0                    | 12.4                     | 6.9        | 5.6        | 1.6        | 8.0        | 12.0      | Q1               |

**PACKAGE MATERIALS INFORMATION** 

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#### \*All dimensions are nominal

| Device        | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|---------------|--------------|-----------------|------|------|-------------|------------|-------------|
| MAX3232MDBREP | SSOP         | DB              | 16   | 2000 | 367.0       | 367.0      | 38.0        |
| MAX3232MPWREP | TSSOP        | PW              | 16   | 2000 | 356.0       | 356.0      | 35.0        |





#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



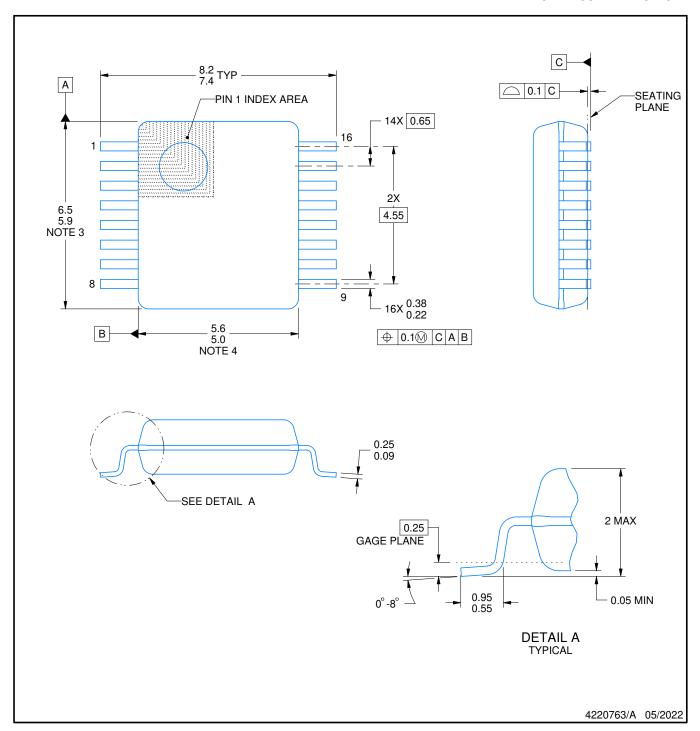


NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.







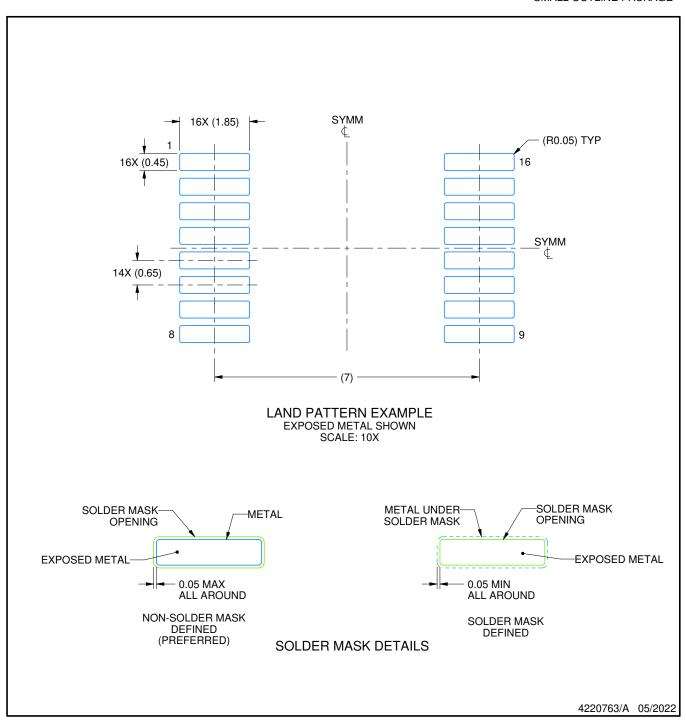
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- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
  4. Reference JEDEC registration MO-150.



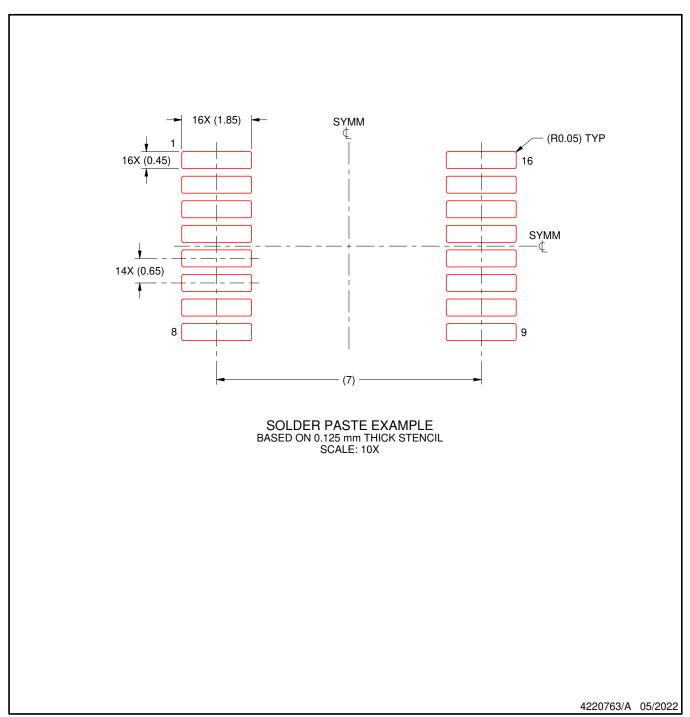


NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

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- 8. Board assembly site may have different recommendations for stencil design.



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